\bigcirc

SF51G THRU SF58G

Super Fast Recovery Rectifier

Features

- Ultrafast reverse recovery time
- Low leakage current
- Low switching losses, high efficiency
- High forward surge capability
- Glass passivated chip junction
- Solder dip 275 °C max. 7 s, per JESD 22-B106

Typical Applications

For use in high frequency rectification and freewheeling application in switching mode converters and inverters for consumer, computer and telecommunication.

Mechanical Data

- Package: DO-201AD(DO-27)
 - Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant
- Terminals: Tin plated leads, solderable per J-STD-002 and JESD22-B102
- Polarity: Color band denotes the cathode end

■Maximum Ratings (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	SF51G	SF52G	SF53G	SF54G	SF55G	SF56G	SF57G	SF58G
Device marking code			SF51G	SF52G	SF53G	SF54G	SF55G	SF56G	SF57G	SF58G
Maximum Repetitive Peak Reverse Voltage	V _{RRM}	V	50	100	150	200	300	400	500	600
Maximum RMS Voltage	V _{RMS}	V	35	70	105	140	210	280	350	420
Maximum DC blocking Voltage	V _{DC}	V	50	100	150	200	300	400	500	600
Average Forward Current @60Hz sine wave, Resistance load, Ta =60°C	I _{F(AV)}	A	5.0							
Forward Surge Current (Non-repetitive) @60Hz Half-sine wave,1 cycle, Tj=25℃			150							
Forward Surge Current (Non-repetitive) @1ms, square wave, 1 cycle, Tj=25℃	IFSM	A	250							
Current squared time @1ms≤t8.3≤ms Tj=25℃,Rating of per diode	l ² t	A²s	94							
Typical junction capacitance @Measured at 1MHz and Applied Reverse Voltage of 4.0 V.D.C	Cj	pF	80 46 30			0				
Storage Temperature	T _{stg}	°C	-55 ~ +150							
Junction Temperature	Тј	°C	-55 ~ +150							

Electrical Characteristics (T_a =25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	SF51G	SF52G	SF53G	SF54G	SF55G	SF56G	SF57G	SF58G
Maximum instantaneous forward voltage drop per diode	VF	V	IFM=5.0A	0.95			1.3		1.7		
Maximum DC reverse current at rated DC blocking voltage per	IR	μA	Tj =25℃ 2.5								
diode	чК	μΑ	Tj =125℃	100							
Maximum reverse recovery time	trr	ns	I _F =0.5A,I _R =1.0A, I _r =0.25A	35							



SF51G THRU SF58G

■Thermal Characteristics (T_a=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	SF51G	SF52G	SF53G	SF54G	SF55G	SF56G	SF57G	SF58G
Typical Thermal Resistance	R_{\thetaJ}	°C/W	15							

■Ordering Information (Example)

PREFERED P/N	PACKAGE CODE	UNIT WEIGHT(g)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
SF51G~SF58G	D1	Approximate 1.05	1250	1250	12500	Таре
SF51G~SF58G	C1	Approximate 1.05	250	250	12500	Bulk

Characteristics(Typical)







FIG.4: Typical Reverse Characteristics





SF51G THRU SF58G



FIG.5: Diagram of circuit and Testing wave form of reverse recovery time

Outline Dimensions



DO-201AD(DO-27)							
Dim	Min	Max					
А	8.50	9.50					
В	5.00	5.60					
С	25.4	/					
D	1.20	1.30					



SF51G THRU SF58G

Disclaimer

The information presented in this document is for reference only. Yangzhou Yangjie Electronic Technology Co., Ltd. reserves the right to make changes without notice for the specification of the products displayed herein to improve reliability, function or design or otherwise.

The product listed herein is designed to be used with ordinary electronic equipment or devices, and not designed to be used with equipment or devices which require high level of reliability and the malfunction of with would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), Yangjie or anyone on its behalf, assumes no responsibility or liability for any damages resulting from such improper use of sale.

This publication supersedes & replaces all information previously supplied. For additional information, please visit our website http:// www.21yangjie.com, or consult your nearest Yangjie's sales office for further assistance.